3.3 V FULL-DUPLEX RS-485/RS-422 DRIVERS AND BALANCED RECEIVERS

FEATURES

- **Designed for INTERBUS Applications**
- **Designed for RS-422 and RS-485 Networks**
- **Balanced Receiver Thresholds**
- **1/2 Unit-Load (up to 64 nodes on the bus)**
- **Bus-Pin ESD Protection 15 kV HBM**
- **Bus-Fault Protection of –7 V to 12 V**
- **Thermal Shutdown Protection**
- **Power-Up/Down Glitch-free Bus Inputs and Outputs**
- **High Input Impedance With Low V_{CC}**
- **Monotonic Outputs During Power Cycling**
- **5-V Tolerant Inputs**

APPLICATIONS

- **Digital Motor Control**
- **Utility Meters**
- **Chassis-to-Chassis Interconnections**
- **Electronic Security Stations**
- **Industrial, Process, and Building Automation**
- **Point-of-Sale (POS) Terminals and Networks**
- **DTE/DCE Interfaces**

DESCRIPTION

The SN65HVD379 is a differential line driver and differential-input line receiver that operates with a 3.3-V power supply. Each driver and receiver has separate input and output pins for full-duplex bus communication designs. They are designed for balanced transmission lines and interoperation with ANSI TIA/EIA-485A, TIA/EIA-422-B, ITU-T v.11, and ISO 8482:1993 standard-compliant devices.

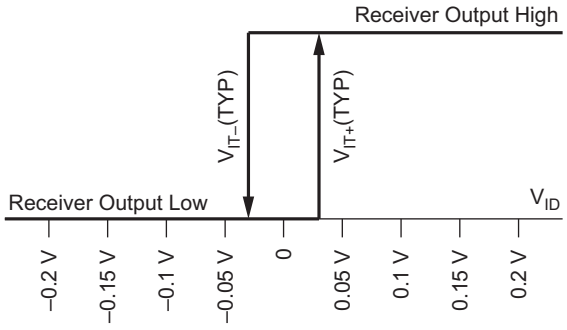
These differential bus drivers and receivers are monolithic, integrated circuits designed for full-duplex bi-directional data communication on multipoint bus-transmission lines at signaling rates(1) up to 25 Mbps. The SN65HVD379 is fully enabled with no external enabling pins.

The 1/2 unit load receiver has a higher receiver input resistance. This results in lower bus leakage currents over the common-mode voltage range, and reduces the total amount of current that an RS-485 driver is forced to source or sink when transmitting.

The balanced differential receiver input threshold makes the SN65HVD379 more compatible with fieldbus requirements that define an external failsafe structure.

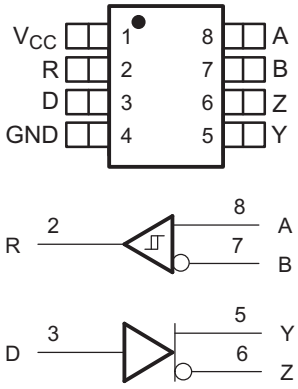
(1) The signaling rate of a line is the number of voltage transitions that are made per second expressed in the units bps (bits per second).

BALANCED RECEIVER INPUT THRESHOLDS



SN65HVD379

D PACKAGE
(TOP VIEW)



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION

SIGNALING RATE	UNIT LOADS	PART NUMBER(1)	SOIC MARKING
25 Mbps	1/2	SN65HVD379	

(1) These are The D package is available taped and reeled. Add an R suffix to the part number (ie. SN65HVD379DR).

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range unless otherwise noted(1) (2)

		UNIT
V_{CC}	Supply voltage range	–0.3 V to 6 V
V_A, V_B, V_Y, V_Z	Voltage range at any bus terminal (A, B, Y, Z)	–9 V to 14 V
V_{TRANS}	Voltage input, transient pulse through 100 Ω. See Figure 8 (A, B, Y, Z)(3)	–50 to 50 V
V_I	Input voltage range (D, DE, $\overline{RE}$)	-0.5 V to 7 V
P_{CONT}	Continuous total power dissipation	Internally limited(4)
I_O	Output current (receiver output only, R)	11 mA

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.
(3) This tests survivability only and the output state of the receiver is not specified.
(4) The Thermal shutdown protection circuit internally limits the continuous total power dissipation. Thermal shutdown typically occurs when the junction temperature reaches 165C.

RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range unless otherwise noted

PARAMETER			MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage		3		3.6	V
V_I or V_{IC}	Voltage at any bus terminal (separately or common mode)		–7(1)		12	V
$1/t_{UI}$	Signaling rate	SN65HVD379			25	Mbps
R_L	Differential load resistance		54	60		Ω
V_{IH}	High-level input voltage	D	2		V_{CC}	V
V_{IL}	Low-level input voltage	D	0		0.8	V
V_{ID}	Differential input voltage		–12		12	V
I_{OH}	High-level output current	Driver	–60			mA
		Receiver	–8			mA
I_{OL}	Low-level output current	Driver			60	mA
		Receiver			8	mA
T_A	Ambient still-air temperature		–40		85	C

(1) The algebraic convention, in which the least positive (most negative) limit is designated as minimum is used in this data sheet.

ELECTROSTATIC DISCHARGE PROTECTION

PARAMETER	TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
Human body model	Bus terminals and GND		16		kV
Human body model(2)	All pins		4		
Charged-device-model(3)	All pins		1		

(1) All typical values at 25C with 3.3-V supply.
(2) Tested in accordance with JEDEC Standard 22, Test Method A114-A.
(3) Tested in accordance with JEDEC Standard 22, Test Method C101.

DRIVER ELECTRICAL CHARACTERISTICS

over recommended operating conditions unless otherwise noted

PARAMETER			TEST CONDITIONS		MIN	TYP(1)	MAX	UNIT
$V_{I(K)}$	Input clamp voltage		I_I = –18 mA		–1.5			V
$\|V_{OD(SS)}\|$	Steady-state differential output voltage		I_O = 0		2		V_{CC}	
			R_L = 54 Ω, See Figure 1 (2)(RS-485)		1.5	2.0		
			R_L = 100 Ω, See Figure 1 (RS-422)		2	2.3		
			V_{test} = –7 V to 12 V, See Figure 2		1.5			
$\Delta\|V_{OD(SS)}\|$	Change in magnitude of steady-state differential output voltage between states		R_L = 54 Ω, See Figure 1 and Figure 2		–0.2		0.2	
$V_{OD(RING)}$	Differential output voltage overshoot and undershoot		R_L = 54 Ω, C_L = 50 pF, See Figure 5 (Figure 3 for definitions)				10%(3)	
$V_{OC(PP)}$	Peak-to-peak common-mode output voltage		See Figure 3			0.5		
$V_{OC(SS)}$	Steady-state common-mode output voltage				1.6		2.3	
$\Delta V_{OC(SS)}$	Change in steady-state common-mode output voltage				–0.05		0.05	
$I_{Z(Z)}$ or $I_{Y(Z)}$	High-impedance state output current		V_{CC} = 0 V, V_Z or V_Y = 12 V, Other input at 0 V				90	µA
			V_{CC} = 0 V, V_Z or V_Y = –7 V, Other input at 0 V		–10			
$I_{Z(S)}$ or $I_{Y(S)}$	Short-circuit output current(4)		V_Z or V_Y = –7 V	Other input at 0 V	–250		250	mA
			V_Z or V_Y = 12 V		–250		250	
I_I	Input current	D	V_I = 0 or V_I = 2.0		0		100	A
$C_{(OD)}$	Differential output capacitance		V_{OD} = 0.4 sin (4E6πt) + 0.5 V, V_{CC} at 0 V			16		pF

(1) All typical values are at 25C and with a 3.3-V supply.
(2) V_{CC} is 3.3 Vdc 5%
(3) 10% of the peak-to-peak differential-output voltage swing, per TIA/EIA-485.
(4) Under some conditions of short-circuit to negative voltages, output currents exceeding the ANSI TIA/EIA-485-A maximum current of 250 mA may occur. Continuous exposure may affect device reliability.

DRIVER SWITCHING CHARACTERISTICS

over recommended operating conditions unless otherwise noted

PARAMETER		TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
t_{PLH}	Propagation delay time, low-to-high-level output	R_L = 54 Ω, C_L = 50 pF, See Figure 5	4	10	18	ns
t_{PHL}	Propagation delay time, high-to-low-level output					
t_r	Differential output signal rise time		2.5	5	12	ns
t_f	Differential output signal fall time					
$t_{sk(p)}$	Pulse skew ($\|t_{PHL} - t_{PLH}\|$)			0.6		ns
$t_{sk(pp)}$ (2)	Part-to-part skew			1		ns

(1) All typical values are at 25C and with a 3.3-V supply.
(2) $t_{sk(pp)}$ is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

RECEIVER ELECTRICAL CHARACTERISTICS

over recommended operating conditions unless otherwise noted

PARAMETER		TEST CONDITIONS		MIN	TYP(1)	MAX	UNIT
V_{IT+}	Positive-going differential input threshold voltage	I_O = –8 mA				0.2	V
$V_{IT–}$	Negative-going differential input threshold voltage	I_O = 8 mA		–0.2			V
V_{hys}	Hysteresis voltage ($V_{IT+} – V_{IT–}$)				50		mV
V_O	Output voltage	V_{ID} = 200 mV, I_O = –8 mA, See Figure 7		2.4			V
		V_{ID} = –200 mV, I_O = 8 mA, See Figure 7				0.4	
I_A or I_B	Bus input current	V_A or V_B = 12 V	Other input at 0 V		0.20	0.35	mA
		V_A or V_B = 12 V, V_{CC} = 0 V			0.24	0.40	
		V_A or V_B = -7 V		–0.35	–0.18		
		V_A or V_B = -7 V, V_{CC} = 0 V		–0.25	–0.13		
C_{ID}	Differential input capacitance	V_{ID} = 0.4 sin (4E6πt) + 0.5 V, DE at 0 V			15		pF
I_{CC}	Supply current	D at 0 V or V_{CC} and No Load				2.1	mA

(1) All typical values are at 25C and with a 3.3-V supply.

RECEIVER SWITCHING CHARACTERISTICS

over recommended operating conditions unless otherwise noted

PARAMETER		TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
t_{PLH}	Propagation delay time, low-to-high-level output	V_{ID} = –1.5 V to 1.5 V, C_L = 15 pF, See Figure 7		26	45	ns
t_{PHL}	Propagation delay time, high-to-low-level output					
$t_{sk(p)}$	Pulse skew ($\|t_{PHL} - t_{PLH}\|$)				7	
$t_{sk(pp)}$	Part-to-part skew(2)			5		
t_r	Output signal rise time				5	
t_f	Output signal fall time				6	

(1) All typical values are at 25C and with a 3.3-V supply

(2) $t_{sk(pp)}$ is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

DEVICE POWER DISSIPATION – P_D

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
P_D	Device power dissipation	R_L = 60 , C_L = 50 pF, Input to D a 50% duty cycle square wave at indicated signaling rate T_A = 85C			197	mW

FUNCTION TABLES

DRIVER			RECEIVER	
INPUT	OUTPUTS		DIFFERENTIAL INPUTS	OUTPUTS
D	Y	Z	$V_{ID} = V_A–V_B$	R
H	H	L	V_{ID} ≤ –0.2 V	L
L	L	H	–0.2 V < V_{ID} < 0.2 V	?
Open	L	H	0.2 V ≤ V_{ID}	H

PARAMETER MEASUREMENT INFORMATION

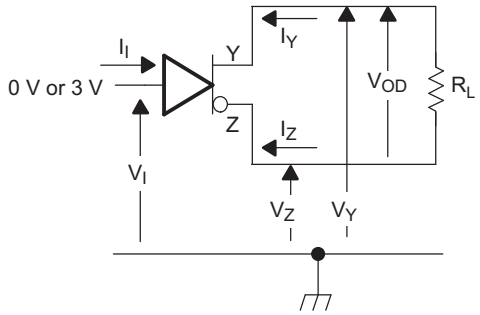


Figure 1. Driver V_{OD} Test Circuit and Voltage and Current Definitions

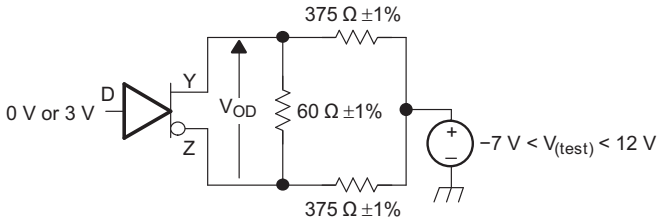


Figure 2. Driver V_{OD} With Common-Mode Loading Test Circuit

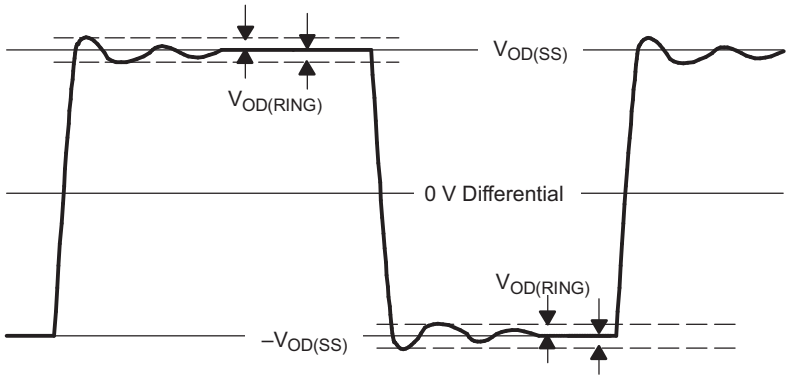
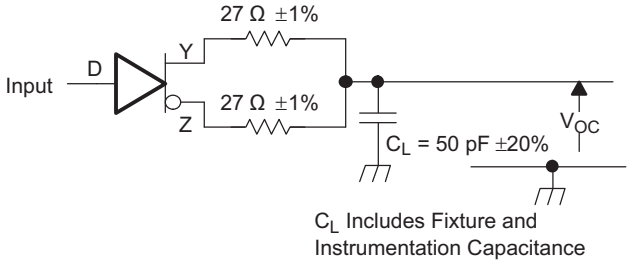
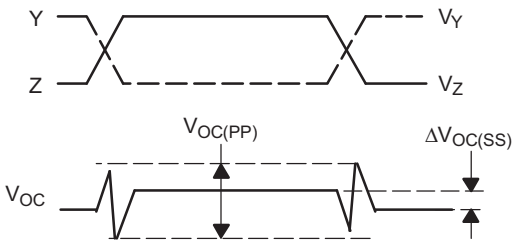


Figure 3. $V_{OD(RING)}$ Waveform and Definitions

$V_{OD(RING)}$ is measured at four points on the output waveform, corresponding to overshoot and undershoot from the$V_{OD(H)}$ and $V_{OD(L)}$ steady state values.

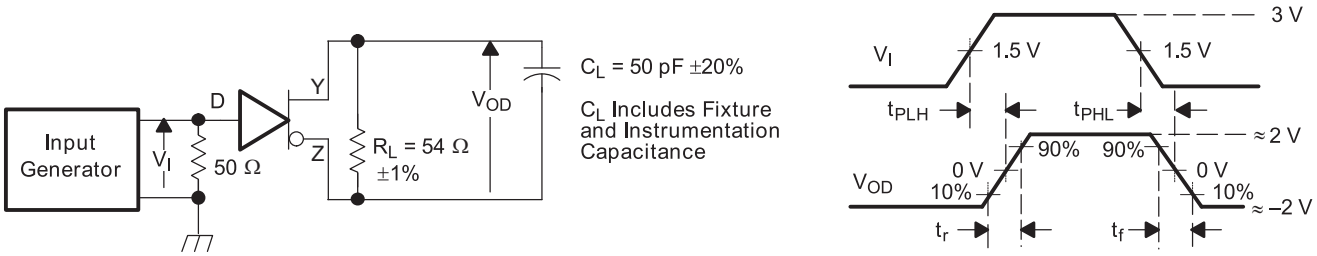




Input: PRR = 500 kHz, 50% Duty Cycle, t_r < 6 ns, t_f < 6 ns, Z_O = 50 Ω

Figure 4. Test Circuit and Definitions for the Driver Common-Mode Output Voltage

PARAMETER MEASUREMENT INFORMATION (continued)



Generator: PRR = 500 kHz, 50% Duty Cycle, t_r < 6 ns, t_f < 6 ns, Z_O = 50 Ω

Figure 5. Driver Switching Test Circuit and Voltage Waveforms

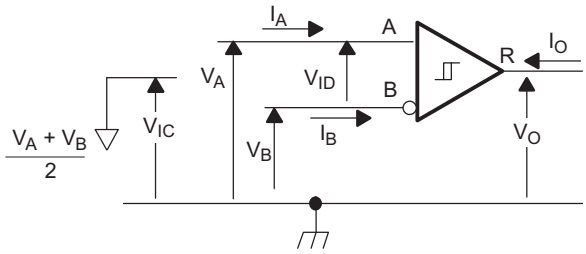
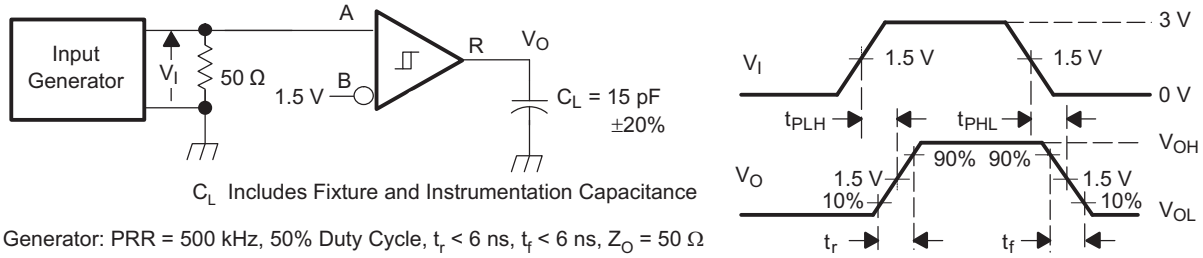


Figure 6. Receiver Voltage and Current Definitions



Generator: PRR = 500 kHz, 50% Duty Cycle, t_r < 6 ns, t_f < 6 ns, Z_O = 50 Ω

Figure 7. Receiver Switching Test Circuit and Voltage Waveforms

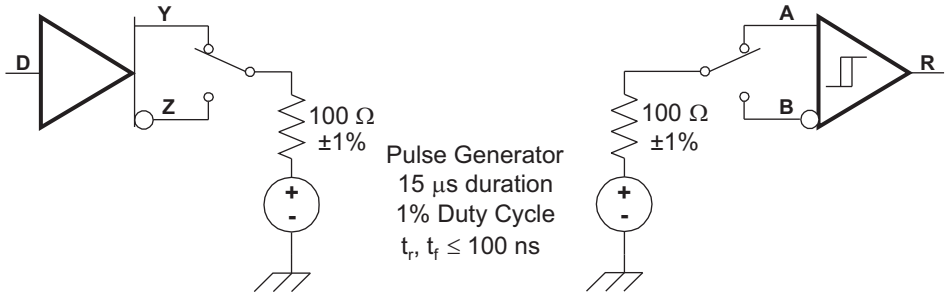
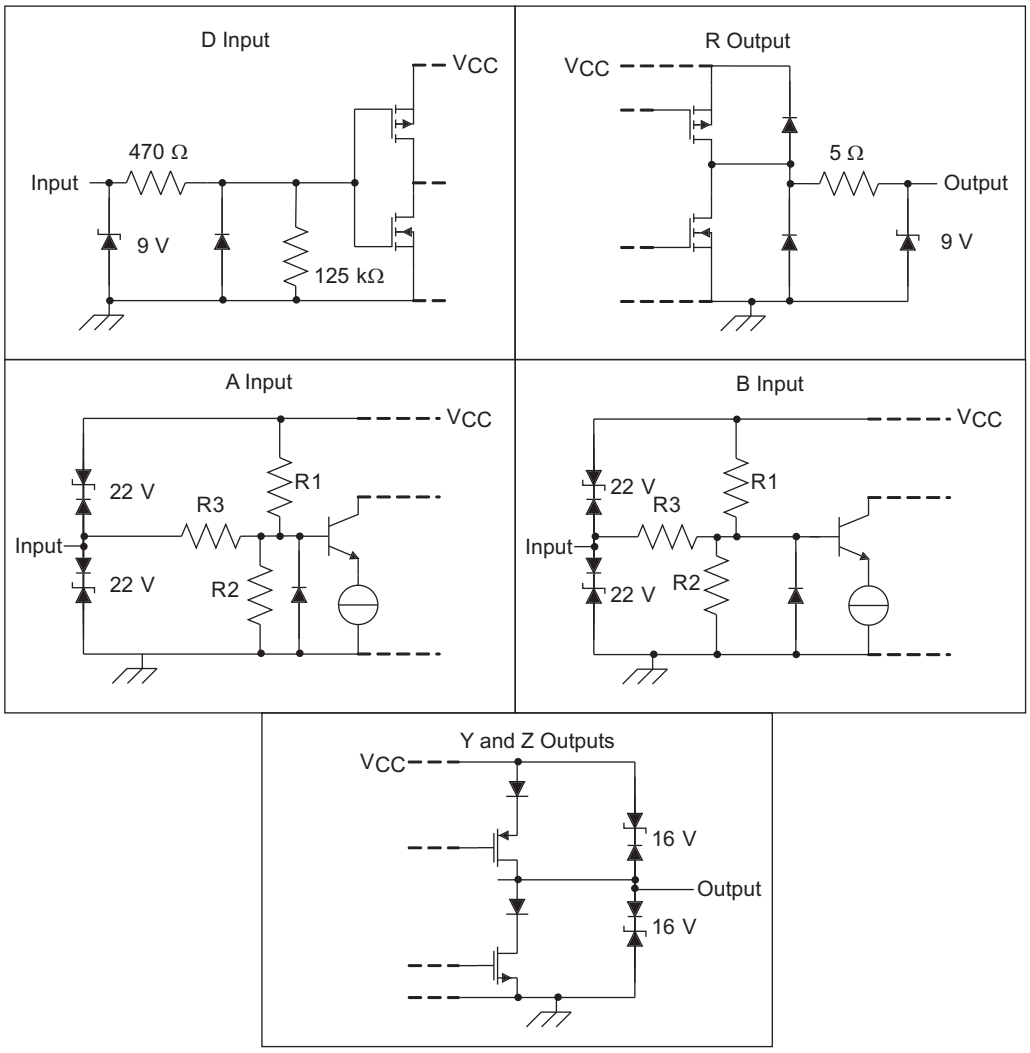


Figure 8. Test Circuit, Transient Over Voltage Test

EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS



	R1/R2	R3
SN65HVD379	9 kΩ	45 kΩ

TYPICAL CHARACTERISTICS

RMS SUPPLY CURRENT vs SIGNALING RATE

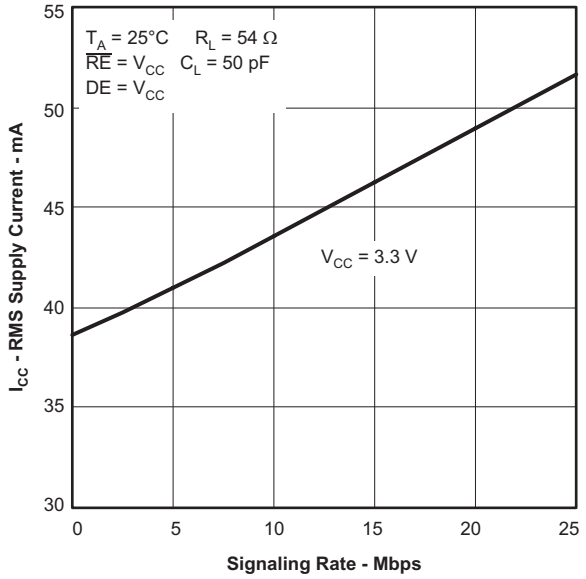


Figure 9.

BUS INPUT CURRENT vs BUS INPUT VOLTAGE

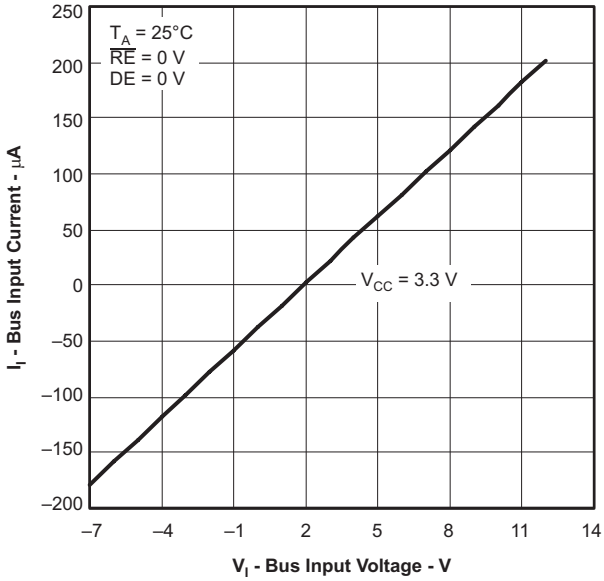


Figure 10.

DRIVER LOW-LEVEL OUTPUT CURRENT vs LOW-LEVEL OUTPUT VOLTAGE

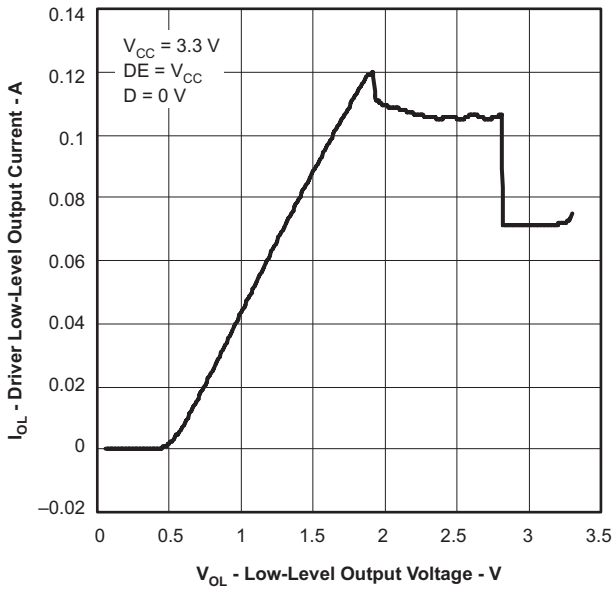


Figure 11.

DRIVER HIGH-LEVEL OUTPUT CURRENT vs HIGH-LEVEL OUTPUT VOLTAGE

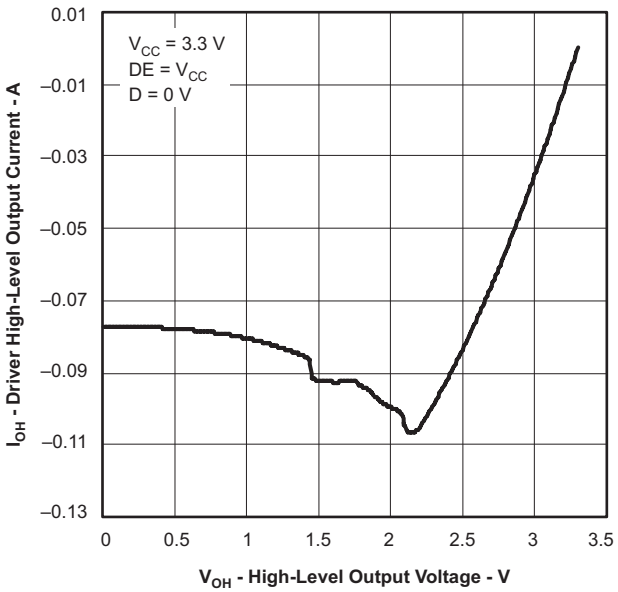


Figure 12.

TYPICAL CHARACTERISTICS (continued)

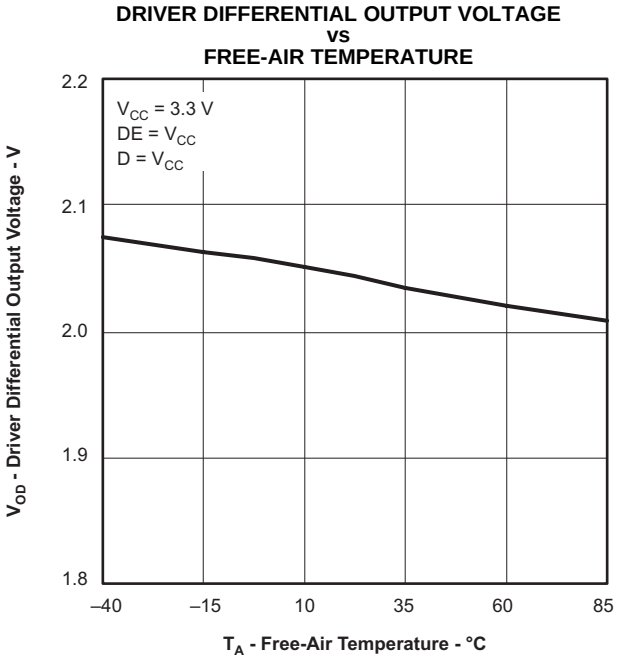


Figure 13.

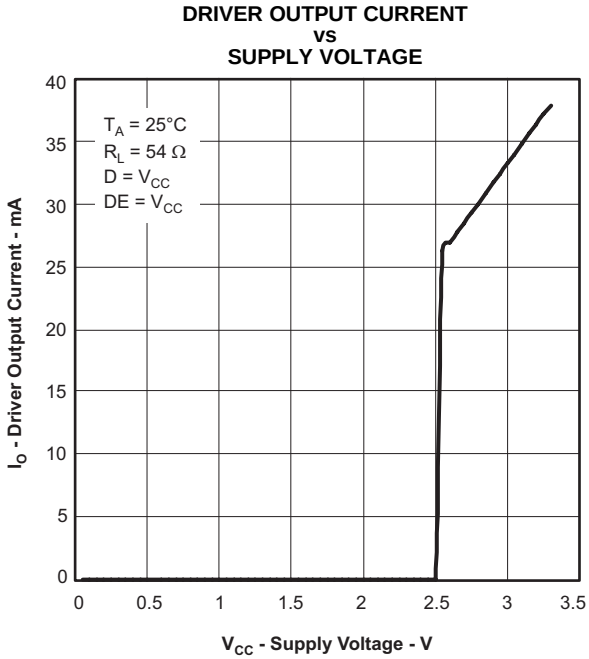


Figure 14.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN65HVD379D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VP379	Samples
SN65HVD379DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VP379	Samples
SN65HVD379DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VP379	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

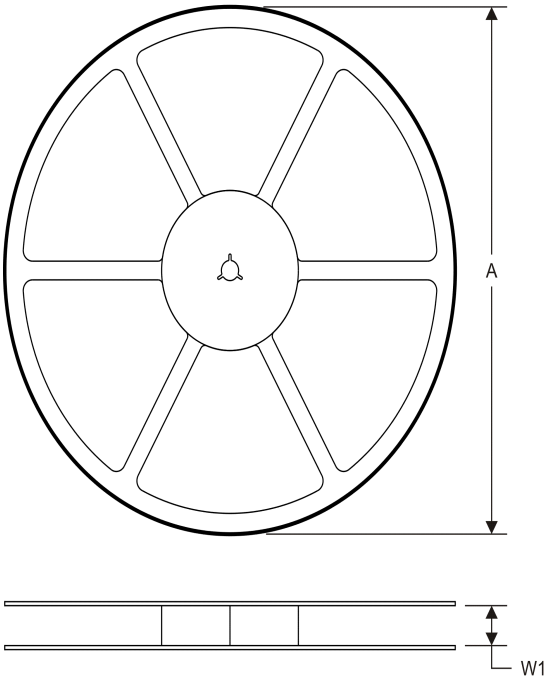
(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

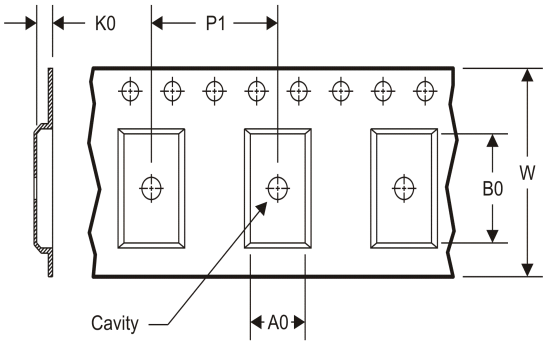
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



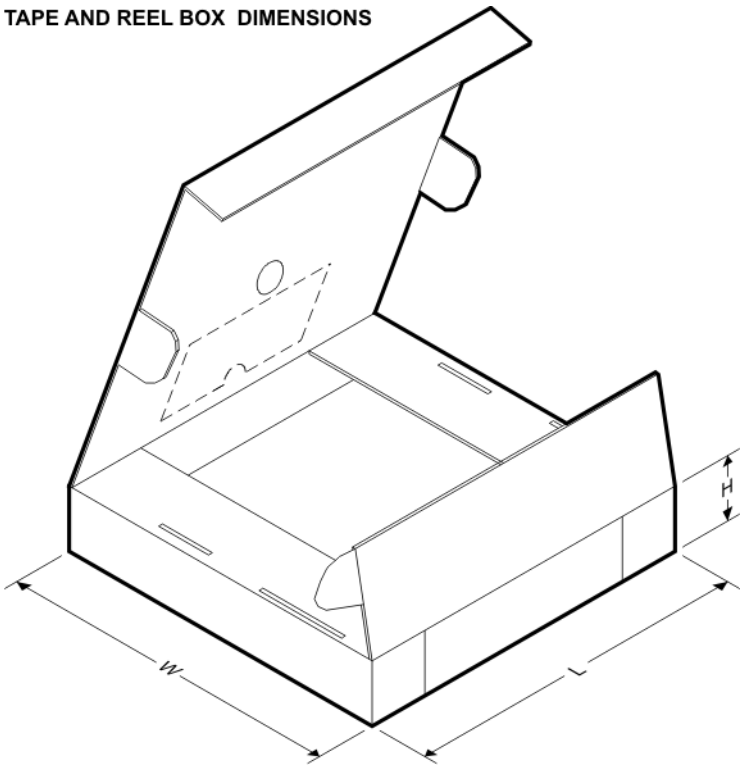
A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

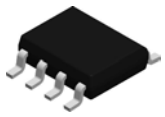
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65HVD379DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65HVD379DR	SOIC	D	8	2500	367.0	367.0	35.0

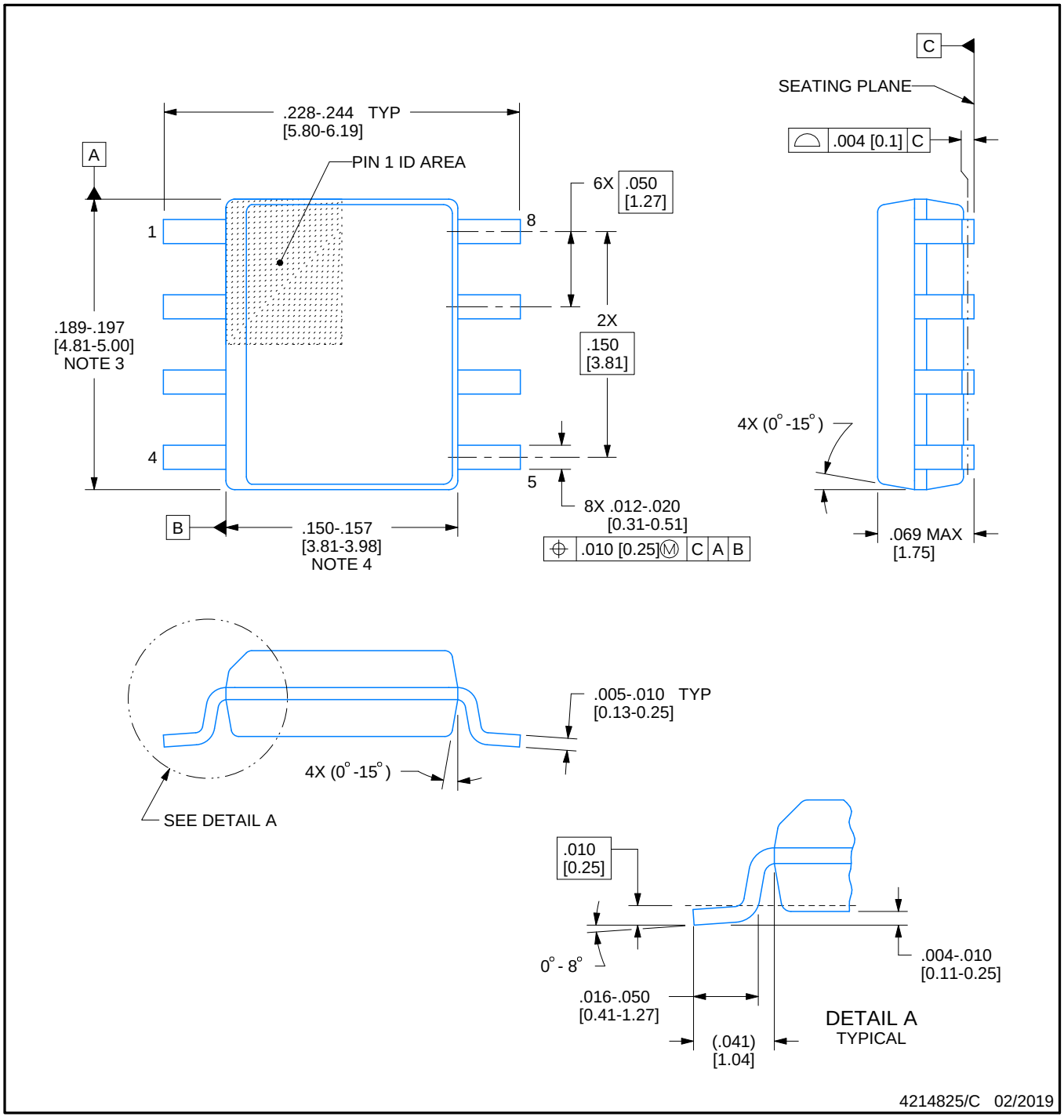


PACKAGE OUTLINE

D0008A

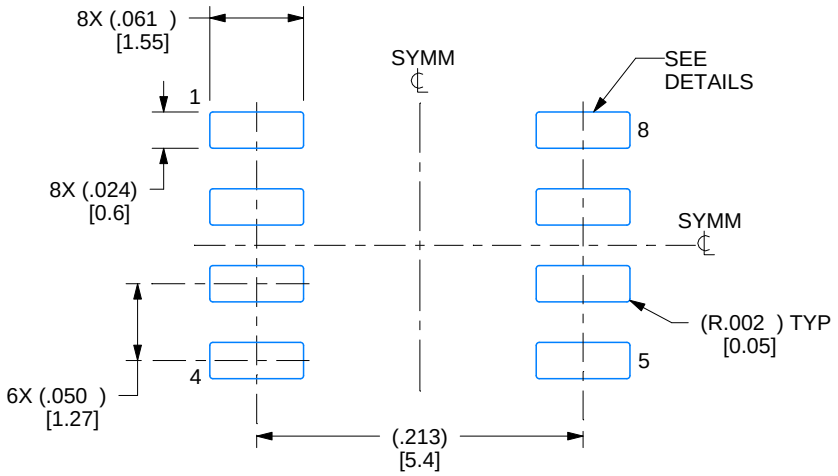
SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

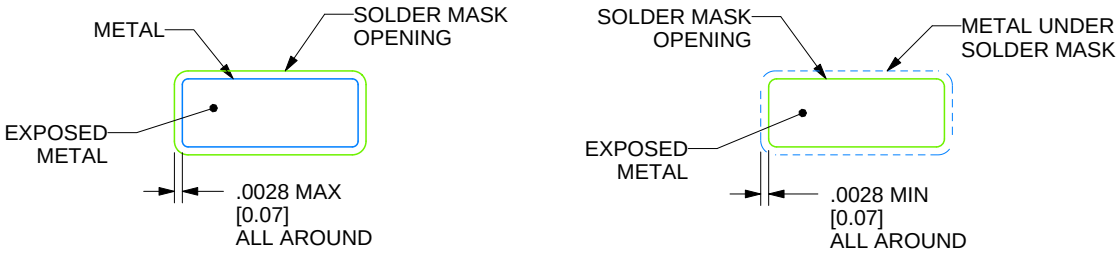


NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

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NOTES: (continued)

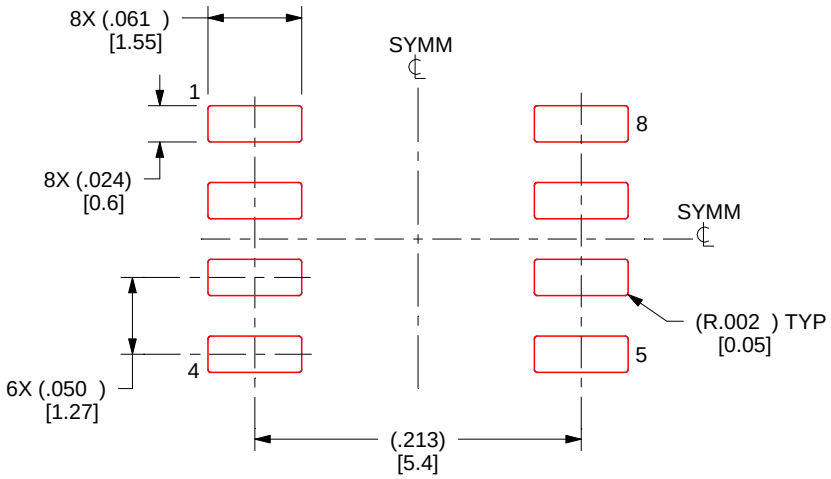
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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